## **EEPROM, Serial, 4-Kb, 8-Kb** and 16-Kb I<sup>2</sup>C, Low Voltage Automotive Grade 1

# NV24C04LV, NV24C08LV, NV24C16LV

## Description

The NV24C04/08/16LV are 4–Kb, 8–Kb and 16–Kb respectively CMOS Serial EEPROM devices that operate at a minimum 1.7 V supply voltage. They are organized internally as 16/32/64 and 128 pages respectively of 16 bytes each. All devices support the Standard (100 kHz), Fast (400 kHz) and Fast–Plus (1 MHz) I<sup>2</sup>C protocol.

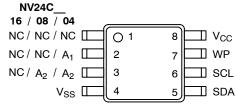
Data is written by providing a starting address, then loading 1 to 16 contiguous bytes into a Page Write Buffer, and then writing all data to non-volatile memory in one internal write cycle. Data is read by providing a starting address and then shifting out data serially while automatically incrementing the internal address count.

External address pins make it possible to address up to four NV24C04, two NV24C08 and one NV24C16 device on the same bus.

## Features

- Automotive AEC-Q100 Grade 1 (-40°C to +125°C) Qualified
- Supports Standard, Fast and Fast-Plus I<sup>2</sup>C Protocol
- 1.7 V to 5.5 V Supply Voltage Range
- 16-Byte Page Write Buffer
- Fast Write Time (4 ms max)
- Hardware Write Protection for Entire Memory
- Schmitt Triggers and Noise Suppression Filters on I<sup>2</sup>C Bus Inputs (SCL and SDA)
- Low power CMOS Technology
- More than 1,000,000 Program/Erase Cycles
- 100 Year Data Retention
- Automotive Grade 1 Temperature Range
- SOIC, TSSOP, US 8–Lead, TSOP–5 Lead and Wettable Flank UDFN 8–pad Packages
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

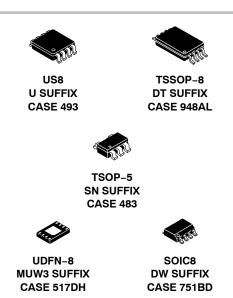
## PIN CONFIGURATION (SOIC-8,US-8,UNFN-8,TSSOP-8)





## **ON Semiconductor®**

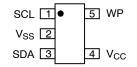
www.onsemi.com

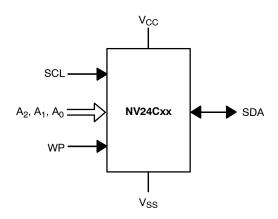


## **ORDERING INFORMATION**

See detailed ordering, marking and shipping information in the package dimensions section on page 14 of this data sheet.

## **PIN CONFIGURATION (TSOP-5)**





## Figure 1. Functional Symbol

### Table 2. ABSOLUTE MAXIMUM RATINGS

Table 1. PIN FUNCTION		l	able	1.	PIN	FUN	CTION	
-----------------------	--	---	------	----	-----	-----	-------	--

Pin Name	Function
A0, A1, A2	Device Address Input
SDA	Serial Data Input/Output
SCL	Serial Clock Input
WP	Write Protect Input
V <sub>CC</sub>	Power Supply
V <sub>SS</sub>	Ground
NC	No Connect

Parameters	Ratings	Units
Storage Temperature	–65 to +150	°C
Voltage on any pin with respect to Ground (Note 1)	-0.5 to +6.5	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

 During input transitions, voltage undershoot on any pin should not exceed –1 V for more than 20 ns. Voltage overshoot on pins A<sub>0</sub>, A<sub>1</sub>, A<sub>2</sub> and WP should not exceed V<sub>CC</sub> + 1 V for more than 20 ns, while voltage on the I<sup>2</sup>C bus pins, SCL and SDA, should not exceed the absolute maximum ratings, irrespective of V<sub>CC</sub>.

## Table 3. RELIABILITY CHARACTERISTICS

Symbol	Parameter	Min	Units
N <sub>END</sub> (Note 2)	Endurance	1,000,000	Write Cycles (Note 3)
T <sub>DR</sub> (Note 2)	Data Retention	100	Years

2.  $T_A = 25^{\circ}C$ 

3. A Write Cycle refers to writing a Byte or a Page.

## Table 4. D.C. OPERATING CHARACTERISTICS (V<sub>CC</sub> = 1.7 V to 5.5 V, T<sub>A</sub> = -40°C to +125°C, unless otherwise specified.\*)

						,
Symbol	Parameter	Test Conditions		Min	Мах	Units
I <sub>CCR</sub>	Read Current	Read, f <sub>SCL</sub> = 1 MHz			0.3	mA
Iccw	Write Current	Write			0.5	mA
I <sub>SB</sub>	Standby Current	All I/O Pins at GND or $V_{\mbox{CC}}$	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		1	μA
			$T_A = -40^{\circ}C \text{ to } +125^{\circ}C$		2	
۱L	I/O Pin Leakage	Pin at GND or V <sub>CC</sub>			2	μΑ
V <sub>IL1</sub>	Input Low Voltage	$2.2~V \leq V_{CC} \leq 5.5~V$		-0.5	0.3 V <sub>CC</sub>	V
V <sub>IL2</sub>	Input Low Voltage	$1.7 \text{ V} \le \text{V}_{\text{CC}} < 2.2 \text{ V}$		-0.5	0.2 V <sub>CC</sub>	V
V <sub>IH1</sub>	Input High Voltage	$2.2~V \leq V_{CC} \leq 5.5~V$		0.7 V <sub>CC</sub>	V <sub>CC</sub> + 0.5	V
V <sub>IH2</sub>	Input High Voltage	$1.7 \text{ V} \le \text{V}_{\text{CC}} < 2.2 \text{ V}$		0.8 V <sub>CC</sub>	V <sub>CC</sub> + 0.5	V
V <sub>OL1</sub>	Output Low Voltage	$V_{CC} \geq 2.2$ V, $I_{OL}$ = 6.0 mA			0.4	V
V <sub>OL2</sub>	Output Low Voltage	$V_{CC}$ < 2.2 V, $I_{OL}$ = 2.0 mA			0.2	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

 $*V_{CC(min)} = 1.6$  V for Read operations,  $T_A = -20^{\circ}C$  to  $+85^{\circ}C$ .

Symbol	Parameter	Conditions	Max	Units
C <sub>IN</sub> (Note 4)	SDA I/O Pin Capacitance	V <sub>IN</sub> = 0 V	8	pF
C <sub>IN</sub> (Note 4)	Input Capacitance (other pins)	V <sub>IN</sub> = 0 V	6	pF
	WP Input Current, Address Input	$V_{IN} < V_{IH}, V_{CC} = 5.5 V$	50	μΑ
(Note 5)	Current (A0, A1, A2)	$V_{IN} < V_{IH}, V_{CC} = 3.3 V$	35	
		V <sub>IN</sub> < V <sub>IH</sub> , V <sub>CC</sub> = 1.7 V	25	
		V <sub>IN</sub> > V <sub>IH</sub>	2	

4. These parameters are tested initially and after a design or process change that affects the parameter according to appropriate AEC-Q100 and JEDEC test methods.

5. When not driven, the WP, A0, A1 and A2 pins are pulled down to GND internally. For improved noise immunity, the internal pull-down is relatively Strong; therefore the external driver must be able to supply the pull-down current when attempting to drive the input HIGH. To conserve power, as the input level exceeds the trip point of the CMOS input buffer (~ 0.5 x V<sub>CC</sub>), the strong pull-down reverts to a weak current source.
\*V<sub>CC(min)</sub> = 1.6 V for Read operations, T<sub>A</sub> = -20°C to +85°C.

Table 6. A.C. CHARACTERISTICS V <sub>CC</sub> = 1.7 V to 5.5 V, 7	$\dot{A} = -40^{\circ}$ C to +125°C, unless otherwise specified.*) (Note 6)
---	---

		Standard		Fast		Fast-Plus		
Symbol	Parameter	Min	Max	Min	Max	Min	Max	Units
F <sub>SCL</sub>	Clock Frequency		100		400		1,000	kHz
t <sub>HD:STA</sub>	START Condition Hold Time	4		0.6		0.26		μs
t <sub>LOW</sub>	Low Period of SCL Clock	4.7		1.3		0.50		μs
thigh	High Period of SCL Clock	4		0.6		0.26		μs
t <sub>SU:STA</sub>	START Condition Setup Time	4.7		0.6		0.26		μs
t <sub>HD:DAT</sub>	Data In Hold Time	0		0		0		μs
t <sub>SU:DAT</sub>	Data In Setup Time	250		100		50		ns
t <sub>R</sub> (Note 7)	SDA and SCL Rise Time		1,000		300		120	ns
t <sub>F</sub> (Note 7)	SDA and SCL Fall Time		300		300		120	ns
t <sub>SU:STO</sub>	STOP Condition Setup Time	4		0.6		0.26		μs
t <sub>BUF</sub>	Bus Free Time Between STOP and START	4.7		1.3		0.5		μs
t <sub>AA</sub>	SCL Low to Data Out Valid		3.5		0.9		0.45	μs
t <sub>DH</sub> (Note 7)	Data Out Hold Time	100		100		50		ns
T <sub>i</sub> (Note 7)	Noise Pulse Filtered at SCL and SDA Inputs		50		50		50	ns
t <sub>SU:WP</sub>	WP Setup Time	0		0		0		μs
t <sub>HD:WP</sub>	WP Hold Time	2.5		2.5		1		μs
t <sub>WR</sub>	Write Cycle Time		4		4		4	ms
t <sub>PU</sub> (Notes 7, 8)	Power-up to Ready Mode		0.35		0.35		0.35	ms

6. Test conditions according to "A.C. Test Conditions" table.

7. Tested initially and after  $\ddot{a}$  design or process change that affects this parameter.

8. t<sub>PU</sub> is the delay between the time V<sub>CC</sub> is stable and the device is ready to accept commands. \*V<sub>CC(min)</sub> = 1.6 V for Read operations,  $T_A = -20^{\circ}C$  to +85°C.

Input Levels	$\begin{array}{c} 0.2 \ x \ V_{CC} \ to \ 0.8 \ x \ V_{CC} \ for \ V_{CC} \geq 2.2 \ V \\ 0.15 \ x \ V_{CC} \ to \ 0.85 \ x \ V_{CC} \ for \ V_{CC} < 2.2 \ V \end{array}$
Input Rise and Fall Times	≤ 50 ns
Input Reference Levels	$0.3 \times V_{CC}, 0.7 \times V_{CC}$
Output Reference Levels	$0.3 \times V_{CC}, 0.7 \times V_{CC}$
Output Load	Current Source: I <sub>OL</sub> = 6 mA (V <sub>CC</sub> $\ge$ 2.2 V); I <sub>OL</sub> = 2 mA (V <sub>CC</sub> < 2.2 V); C <sub>L</sub> = 100 pF

## Power-On Reset (POR)

Each NV24Cxx\* incorporates Power–On Reset (POR) circuitry which protects the internal logic against powering up in the wrong state.

A NV24Cxx device will power up into Standby mode after  $V_{CC}$  exceeds the POR trigger level and will power down into Reset mode when  $V_{CC}$  drops below the POR trigger level. This bi-directional POR feature protects the device against 'brown-out' failure following a temporary loss of power.

\*For common features, the NV24C04/08/16 will be referred to as NV24Cxx.

## **Pin Description**

**SCL**: The Serial Clock input pin accepts the Serial Clock generated by the Master.

**SDA**: The Serial Data I/O pin receives input data and transmits data stored in EEPROM. In transmit mode, this pin is open drain. Data is acquired on the positive edge, and is delivered on the negative edge of SCL.

**A0, A1 and A2**: The Address inputs set the device address when cascading multiple devices. When not driven, these pins are pulled LOW internally.

**WP**: The Write Protect input pin inhibits all write operations, when pulled HIGH. When not driven, this pin is pulled LOW internally.

## **Functional Description**

The NV24Cxx supports the Inter–Integrated Circuit (I<sup>2</sup>C) Bus data transmission protocol, which defines a device that sends data to the bus as a transmitter and a device receiving data as a receiver. Data flow is controlled by a Master device, which generates the serial clock and all START and STOP conditions. The NV24Cxx acts as a Slave device. Master and Slave alternate as either transmitter or receiver.

## I<sup>2</sup>C Bus Protocol

The I<sup>2</sup>C bus consists of two 'wires', SCL and SDA. The two wires are connected to the  $V_{CC}$  supply via pull–up resistors. Master and Slave devices connect to the 2–wire bus via their respective SCL and SDA pins. The transmitting device pulls down the SDA line to 'transmit' a '0' and releases it to 'transmit' a '1'.

Data transfer may be initiated only when the bus is not busy (see AC Characteristics).

During data transfer, the SDA line must remain stable while the SCL line is high. An SDA transition while SCL is high will be interpreted as a START or STOP condition (Figure 2). The START condition precedes all commands. It consists of a HIGH to LOW transition on SDA while SCL is HIGH. The START acts as a 'wake-up' call to all receivers. Absent a START, a Slave will not respond to commands. The STOP condition completes all commands. It consists of a LOW to HIGH transition on SDA while SCL is HIGH.

**NOTE:** The I/O pins of NV24Cxx do not obstruct the SCL and SDA lines if the VCC supply is switched off. During power-up, the SCL and SDA pins (connected with pull-up resistors to VCC) will follow the VCC monotonically from VSS (0 V) to nominal VCC value, regardless of pull-up resistor value. The delta between the VCC and the instantaneous voltage levels during power ramping will be determined by the relation between bus time constant (determined by pull-up resistance and bus capacitance) and actual VCC ramp rate.

### **Device Addressing**

The Master initiates data transfer by creating a START condition on the bus. The Master then broadcasts an 8-bit serial Slave address. For normal Read/Write operations, the first 4 bits of the Slave address are fixed at 1010 (Ah). The next 3 bits are used as programmable address bits when cascading multiple devices and/or as internal address bits. The last bit of the slave address, R/W, specifies whether a Read (1) or Write (0) operation is to be performed. The 3 address space extension bits are assigned as illustrated in Figure 3.  $A_2$ ,  $A_1$  and  $A_0$  must match the state of the external address pins, and  $a_{10}$ ,  $a_9$  and  $a_8$  are internal address bits.

## Acknowledge

After processing the Slave address, the Slave responds with an acknowledge (ACK) by pulling down the SDA line during the 9th clock cycle (Figure 4). The Slave will also acknowledge the address byte and every data byte presented in Write mode. In Read mode the Slave shifts out a data byte, and then releases the SDA line during the 9<sup>th</sup> clock cycle. As long as the Master acknowledges the data, the Slave will continue transmitting. The Master terminates the session by not acknowledging the last data byte (NoACK) and by issuing a STOP condition. Bus timing is illustrated in Figure 5.

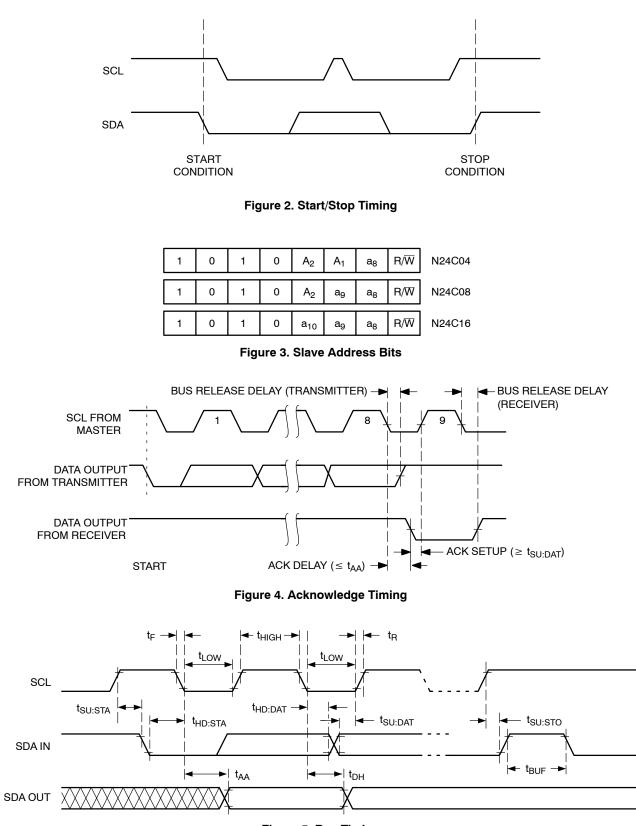


Figure 5. Bus Timing

## WRITE OPERATIONS

### **Byte Write**

In Byte Write mode, the Master sends the START condition and the Slave address with the R/W bit set to zero to the Slave. After the Slave generates an acknowledge, the Master sends the byte address that is to be written into the address pointer of the NV24Cxx. After receiving another acknowledge from the Slave, the Master transmits the data byte to be written into the addressed memory location. The NV24Cxx device will acknowledge the data byte and the Master generates the STOP condition, at which time the device begins its internal Write cycle to nonvolatile memory (Figure 6). While this internal cycle is in progress (t<sub>WR</sub>), the SDA output will be tri–stated and the NV24Cxx will not respond to any request from the Master device (Figure 7).

### Page Write

The NV24Cxx writes up to 16 bytes of data in a single write cycle, using the Page Write operation (Figure 8). The Page Write operation is initiated in the same manner as the Byte Write operation, however instead of terminating after the data byte is transmitted, the Master is allowed to send up to fifteen additional bytes. After each byte has been transmitted the NV24Cxx will respond with an acknowledge and internally increments the four low order address bits. The high order bits that define the page address remain unchanged. If the Master transmits more than sixteen bytes prior to sending the STOP condition, the address counter 'wraps around' to the beginning of page and previously transmitted data will be overwritten. Once all

sixteen bytes are received and the STOP condition has been sent by the Master, the internal Write cycle begins. At this point all received data is written to the NV24Cxx in a single write cycle.

## Acknowledge Polling

The acknowledge (ACK) polling routine can be used to take advantage of the typical write cycle time. Once the stop condition is issued to indicate the end of the host's write operation, the NV24Cxx initiates the internal write cycle. The ACK polling can be initiated immediately. This involves issuing the start condition followed by the slave address for a write operation. If the NV24Cxx is still busy with the write operation, NoACK will be returned. If the NV24Cxx has completed the internal write operation, an ACK will be returned and the host can then proceed with the next read or write operation.

## Hardware Write Protection

With the WP pin held HIGH, the entire memory is protected against Write operations. If the WP pin is left floating or is grounded, it has no impact on the operation of the NV24Cxx. The state of the WP pin is strobed on the last falling edge of SCL immediately preceding the first data byte (Figure 9). If the WP pin is HIGH during the strobe interval, the NV24Cxx will not acknowledge the data byte and the Write request will be rejected.

## **Delivery State**

The NV24Cxx is shipped erased, i.e., all bytes are FFh.

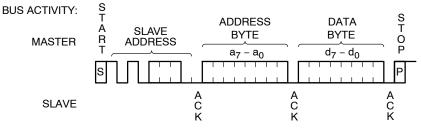
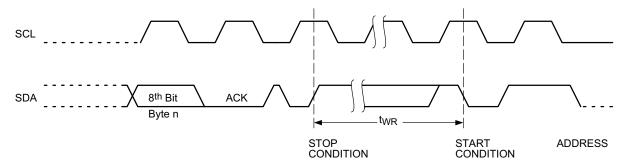
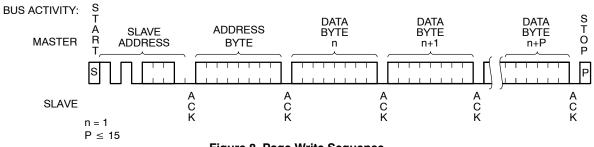


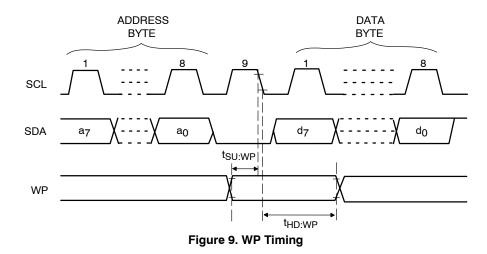
Figure 6. Byte Write Sequence











## **READ OPERATIONS**

#### **Immediate Read**

Upon receiving a Slave address with the R/W bit set to '1', the NV24Cxx will interpret this as a request for data residing at the current byte address in memory. The NV24Cxx will acknowledge the Slave address, will immediately shift out the data residing at the current address, and will then wait for the Master to respond. If the Master does not acknowledge the data (NoACK) and then follows up with a STOP condition (Figure 10), the NV24Cxx returns to Standby mode.

## Selective Read

Selective Read operations allow the Master device to select at random any memory location for a read operation. The Master device first performs a 'dummy' write operation by sending the START condition, slave address and byte address of the location it wishes to read. After the NV24Cxx acknowledges the byte address, the Master device resends the START condition and the slave address, this time with the R/W bit set to one. The NV24Cxx then responds with its acknowledge and sends the requested data byte. The Master device does not acknowledge the data (NoACK) but will generate a STOP condition (Figure 11).

### **Sequential Read**

If during a Read session, the Master acknowledges the 1<sup>st</sup> data byte, then the NV24Cxx will continue transmitting data residing at subsequent locations until the Master responds with a NoACK, followed by a STOP (Figure 12). In contrast to Page Write, during Sequential Read the address count will automatically increment to and then wrap–around at end of memory (rather than end of page).

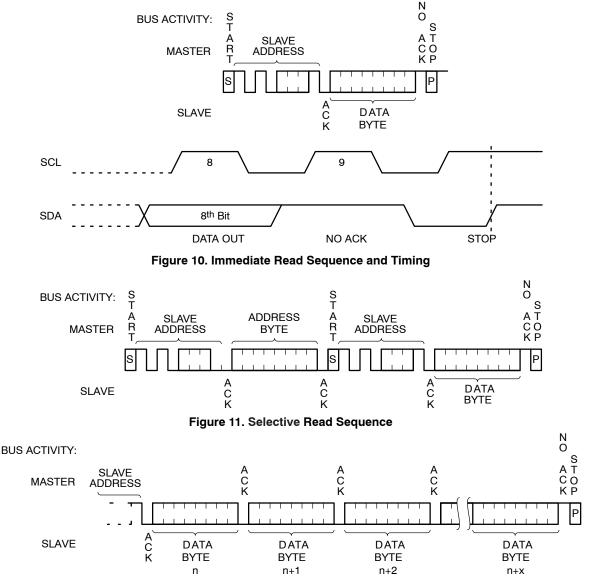
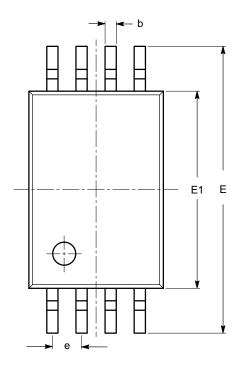


Figure 12. Sequential Read Sequence

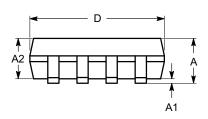
## PACKAGE DIMENSIONS

TSSOP8, 4.4x3 CASE 948AL-01 ISSUE O

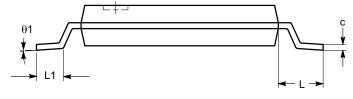


SYMBOL	MIN	NOM	MAX	
А			1.20	
A1	0.05		0.15	
A2	0.80	0.90	1.05	
b	0.19		0.30	
с	0.09		0.20	
D	2.90	3.00	3.10	
E	6.30	6.40	6.50	
E1	4.30	4.40	4.50	
е		0.65 BSC		
L	1.00 REF			
L1	0.50	0.60	0.75	
θ	0°		8°	





SIDE VIEW





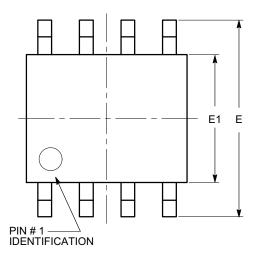
#### Notes:

All dimensions are in millimeters. Angles in degrees.
 Complies with JEDEC MO-153.

### 1. ALL DIMENSIONS ARE IN

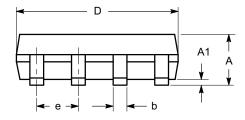
## PACKAGE DIMENSIONS

SOIC 8, 150 mils CASE 751BD-01 ISSUE O



SYMBOL MIN NOM MAX А 1.35 1.75 0.10 0.25 A1 b 0.33 0.51 С 0.19 0.25 D 4.80 5.00 Е 5.80 6.20 E1 3.80 4.00 1.27 BSC е h 0.25 0.50 0.40 1.27 L 0° 8° θ

TOP VIEW

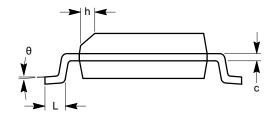


SIDE VIEW

#### Notes:

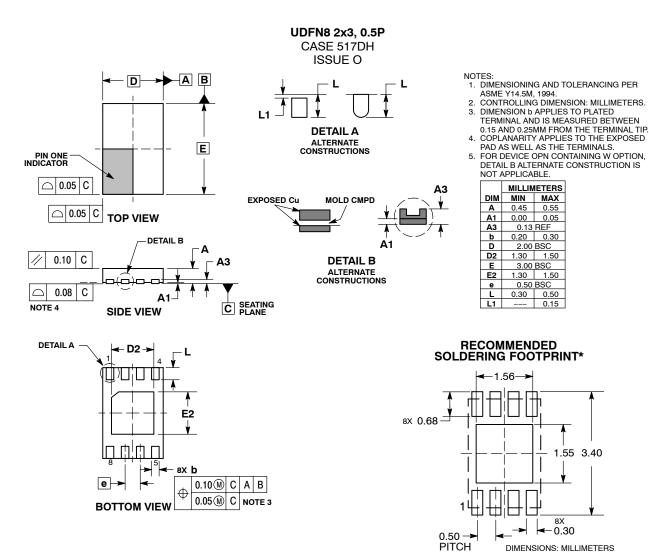
(1) All dimensions are in millimeters. Angles in degrees.

(2) Complies with JEDEC MS-012.



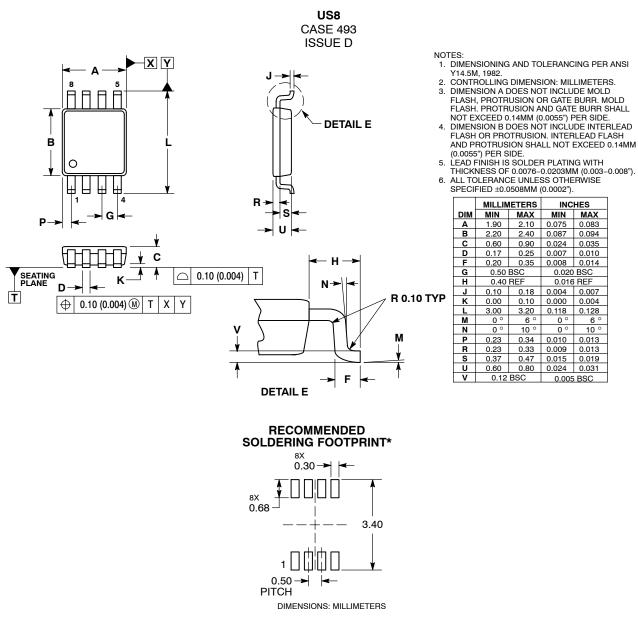
END VIEW

## PACKAGE DIMENSIONS



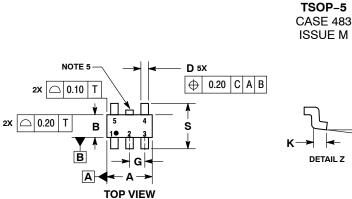
\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## PACKAGE DIMENSIONS



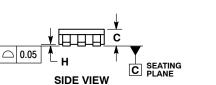
\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

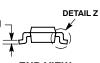
## PACKAGE DIMENSIONS









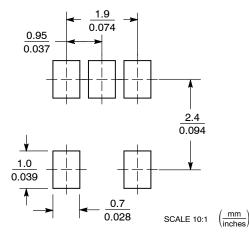


**END VIEW** 

- NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS.
- 3.
- CONTROLLING DIMENSION: MILLIMETERS. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSION A. OPTIONAL CONSTRUCTION: AN ADDITIONAL 4
- 5. OPTIONAL CONSTRUCTION: AN ADDITIONAL TRIMMED LEAD IS ALLOWED IN THIS LOCATION. TRIMMED LEAD NOT TO EXTEND MORE THAN 0.2 FROM RODY

FROM BODY.					
	MILLIMETERS				
DIM	MIN	MAX			
Α	2.85	3.15			
В	1.35 1.65				
С	0.90	1.10			
D	0.25	0.50			
G	0.95 BSC				
н	0.01	0.10			
J	0.10	0.26			
к	0.20	0.60			
м	0 °	10 °			
S	2.50	3.00			

## **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **ORDERING INFORMATION**

OPN	Density (Kb)	Package Type	Temperature Range	Shipping
NV24C04UVLT2G	4	US-8	V = Automotive Grade 1 (-40°C to +125°C)	Tape & Reel, 2,000 Units / Reel
NV24C04MUW3VLTBG	4	UDFN-8 Wettable Flank	V = Automotive Grade 1 (-40°C to +125°C)	Tape & Reel, 3,000 Units / Reel
NV24C04DWVLT3G	4	SOIC-8	V = Automotive Grade 1 (-40°C to +125°C)	Tape & Reel, 3,000 Units / Reel
NV24C04DTVLT3G	4	TSSOP-8	V = Automotive Grade 1 (-40°C to +125°C)	Tape & Reel, 3,000 Units / Reel
NV24C04SNVLT3G*	4	TSOP-5	V = Automotive Grade 1 (-40°C to +125°C)	Tape & Reel, 3,000 Units / Reel
NV24C08UVLT2G	8	US-8	V = Automotive Grade 1 (-40°C to +125°C)	Tape & Reel, 2,000 Units / Reel
NV24C08MUW3VLTBG	8	UDFN-8 Wettable Flank	V = Automotive Grade 1 (-40°C to +125°C)	Tape & Reel, 3,000 Units / Reel
NV24C08DWVLT3G	8	SOIC-8	V = Automotive Grade 1 (-40°C to +125°C)	Tape & Reel, 3,000 Units / Reel
NV24C08DTVLT3G	8	TSSOP-8	V = Automotive Grade 1 (-40°C to +125°C)	Tape & Reel, 3,000 Units / Reel
NV24C08SNVLT3G*	8	TSOP-5	V = Automotive Grade 1 (-40°C to +125°C)	Tape & Reel, 3,000 Units / Reel
NV24C16UVLT2G	16	US-8	V = Automotive Grade 1 (-40°C to +125°C)	Tape & Reel, 2,000 Units / Reel
NV24C16MUW3VLTBG	16	UDFN-8 Wettable Flank	V = Automotive Grade 1 (-40°C to +125°C)	Tape & Reel, 3,000 Units / Reel
NV24C16DWVLT3G	16	SOIC-8	V = Automotive Grade 1 (-40°C to +125°C)	Tape & Reel, 3,000 Units / Reel
NV24C16DTVLT3G	16	TSSOP-8	V = Automotive Grade 1 (-40°C to +125°C)	Tape & Reel, 3,000 Units / Reel
NV24C16SNVLT3G*	16	TSOP-5	V = Automotive Grade 1 (-40°C to +125°C)	Tape & Reel, 3,000 Units / Reel

9. All packages are RoHS-compliant (Lead-free, Halogen-free).

10. For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*Product in development.

#### ON Semiconductor is licensed by Philips Corporation to carry the I<sup>2</sup>C Bus Protocol.

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor dates sheets and/or application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights or others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application. Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and dis

Phone: 421 33 790 2910

#### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative



Компания «Океан Электроники» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Поставка оригинальных импортных электронных компонентов напрямую с производств Америки, Европы и Азии, а так же с крупнейших складов мира;

- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);

- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;

- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком):

- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «JONHON», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «FORSTAR».



«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели, кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



Телефон: 8 (812) 309-75-97 (многоканальный) Факс: 8 (812) 320-03-32 Электронная почта: ocean@oceanchips.ru Web: http://oceanchips.ru/ Адрес: 198099, г. Санкт-Петербург, ул. Калинина, д. 2, корп. 4, лит. А